

# HEF4520B

## Dual binary counter

Rev. 05 — 10 December 2009

Product data sheet

### 1. General description

The HEF4520B is a dual 4-bit internally synchronous binary counter. The counter has an active HIGH clock input ( $nCP0$ ) and an active LOW clock input ( $n\overline{CP1}$ ), buffered outputs from all four bit positions ( $nQ0$  to  $nQ3$ ) and an active HIGH overriding asynchronous master reset input ( $nMR$ ).

The counter advances on either the LOW-to-HIGH transition of the  $nCP0$  input if  $n\overline{CP1}$  is HIGH or the HIGH-to-LOW transition of the  $nCP1$  input if  $nCP0$  is low. Either  $nCP0$  or  $n\overline{CP1}$  may be used as the clock input to the counter while the other clock input may be used as a clock enable input. Schmitt trigger action makes the clock input highly tolerant of slower clock rise and fall times. A HIGH on  $nMR$  resets the counter ( $nQ0$  to  $nQ3 = \text{LOW}$ ) independent of  $nCP0$  and  $n\overline{CP1}$ .

It operates over a recommended  $V_{DD}$  power supply range of 3 V to 15 V referenced to  $V_{SS}$  (usually ground). Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input. It is also suitable for use over the full industrial ( $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ) temperature range.

### 2. Features

- Tolerant of slow clock rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Operates across the full industrial temperature range  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$
- Complies with JEDEC standard JESD 13-B

### 3. Applications

- Industrial

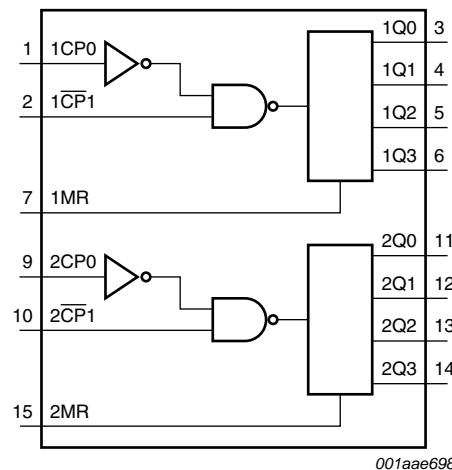
### 4. Ordering information

**Table 1. Ordering information**

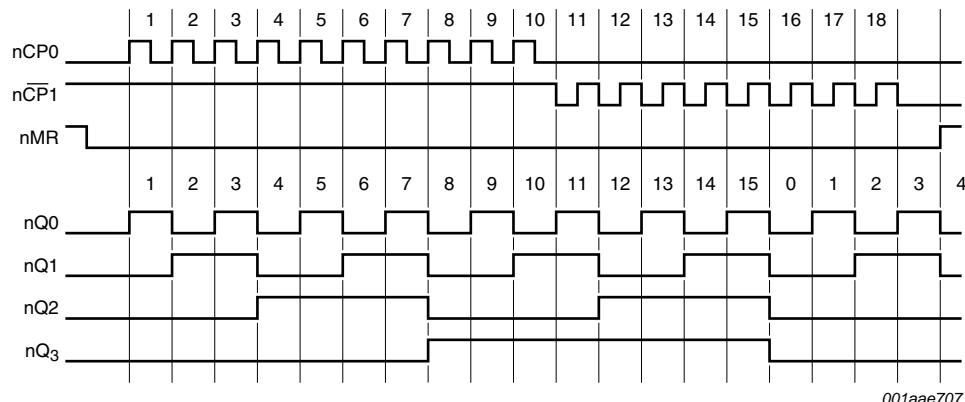
All types operate from  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ .

Type number	Package			Version
	Name	Description		
HEF4520BP	DIP16	plastic dual in-line package; 16 leads (300 mil)		SOT38-4
HEF4520BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm		SOT109-1

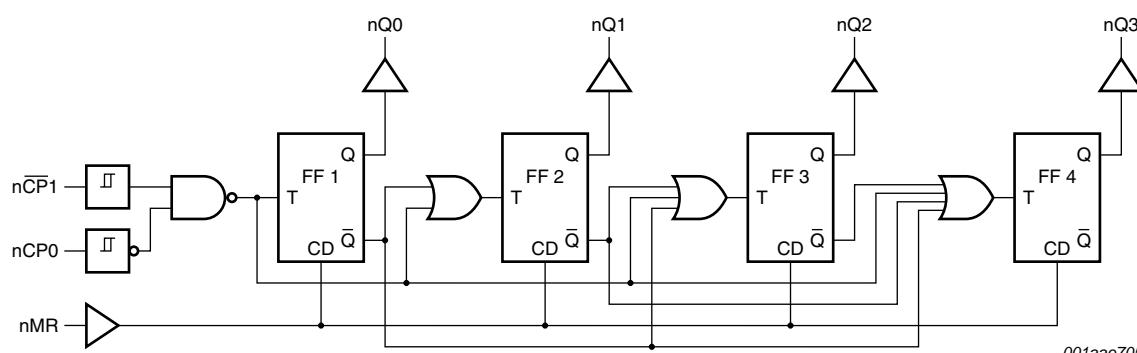
## 5. Functional diagram



**Fig 1.** Functional diagram



**Fig 2.** Timing diagram



**Fig 3.** Logic diagram for one counter

## 6. Pinning information

### 6.1 Pinning

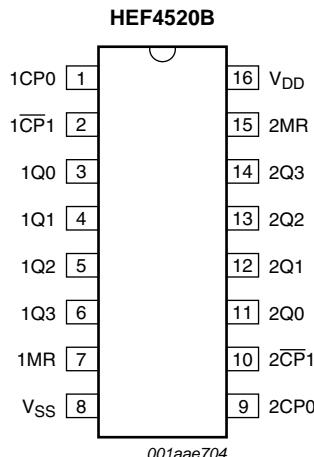


Fig 4. Pin configuration

### 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP0, 2CP0	1, 9	clock input (LOW-to-HIGH triggered)
1CP1, 2CP1	2, 10	clock input (HIGH-to-LOW triggered)
1Q0 to 1Q3	3, 4, 5, 6	output
1MR, 2MR	7, 15	master reset input
V <sub>SS</sub>	8	ground supply voltage
2Q0 to 2Q3	11, 12, 13, 14	output
V <sub>DD</sub>	16	supply voltage

## 7. Functional description

Table 3. Function table<sup>[1]</sup>

nCP0	nCP1	nMR	Mode
↑	H	L	counter advances
L	↓	L	counter advances
↓	X	L	no change
X	↑	L	no change
↑	L	L	no change
H	↓	L	no change
X	X	H	nQ0 to nQ3 = LOW

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; ↑ = positive-going transition; ↓ = negative-going transition.

## 8. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DD</sub>	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>DD</sub> + 0.5 V	-	±10	mA
V <sub>I</sub>	input voltage		-0.5	V <sub>DD</sub> + 0.5	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>DD</sub> + 0.5 V	-	±10	mA
I <sub>I/O</sub>	input/output current		-	±10	mA
I <sub>DD</sub>	supply current		-	50	mA
T <sub>stg</sub>	storage temperature	per output	-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	DIP16 package	[1] -	750	mW
		SO16 package	[2] -	500	mW
P	power dissipation		-	100	mW

[1] For DIP16 package: P<sub>tot</sub> derates linearly with 12 mW/K above 70 °C.

[2] For SO16 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.

## 9. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>DD</sub>	supply voltage		3	-	15	V
V <sub>I</sub>	input voltage		0	-	V <sub>DD</sub>	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V <sub>DD</sub> = 5 V	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

## 10. Static characteristics

**Table 6. Static characteristics**

$V_{SS} = 0 \text{ V}$ ;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	$T_{amb} = -40^\circ\text{C}$		$T_{amb} = 25^\circ\text{C}$		$T_{amb} = 85^\circ\text{C}$		Unit
				Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$ I_O  < 1 \mu\text{A}$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level input voltage	$ I_O  < 1 \mu\text{A}$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
$V_{OH}$	HIGH-level output voltage	$ I_O  < 1 \mu\text{A}; V_I = V_{SS}$ or $V_{DD}$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
$V_{OL}$	LOW-level output voltage	$ I_O  < 1 \mu\text{A}; V_I = V_{SS}$ or $V_{DD}$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
$I_{OH}$	HIGH-level output current	$V_O = 2.5 \text{ V}$	5 V	-1.7	-	-1.4	-	-1.1	-	mA
		$V_O = 4.6 \text{ V}$	5 V	-0.52	-	-0.44	-	-0.36	-	mA
		$V_O = 9.5 \text{ V}$	10 V	-1.3	-	-1.1	-	-0.9	-	mA
		$V_O = 13.5 \text{ V}$	15 V	-3.6	-	-3.0	-	-2.4	-	mA
$I_{OL}$	LOW-level output current	$V_O = 0.4 \text{ V}$	5 V	0.52	-	0.44	-	0.36	-	mA
		$V_O = 0.5 \text{ V}$	10 V	1.3	-	1.1	-	0.9	-	mA
		$V_O = 1.5 \text{ V}$	15 V	3.6	-	3.0	-	2.4	-	mA
$I_I$	input leakage current	$V_{DD} = 15 \text{ V}$	15 V	-	$\pm 0.3$	-	$\pm 0.3$	-	$\pm 1.0$	$\mu\text{A}$
$I_{DD}$	supply current	$I_O = 0 \text{ A}; V_I = V_{SS}$ or $V_{DD}$	5 V	-	20	-	20	-	150	$\mu\text{A}$
			10 V	-	40	-	40	-	300	$\mu\text{A}$
			15 V	-	80	-	80	-	600	$\mu\text{A}$
$C_I$	input capacitance		-	-	-	-	7.5	-	-	pF

## 11. Dynamic characteristics

**Table 7. Dynamic characteristics**

$V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25^\circ\text{C}$ ; for test circuit see [Figure 6](#); unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Typ	Max	Unit
$t_{PHL}$	HIGH to LOW propagation delay	nCP0, $\bar{n}\text{CP1} \rightarrow n\text{Qn}$ ; see <a href="#">Figure 5</a>	5 V	[1] $83 \text{ ns} + (0.55 \text{ ns/pF})C_L$	-	110	220	ns
			10 V	$39 \text{ ns} + (0.23 \text{ ns/pF})C_L$	-	50	100	ns
			15 V	$32 \text{ ns} + (0.16 \text{ ns/pF})C_L$	-	40	80	ns
		nMR $\rightarrow n\text{Qn}$ ; see <a href="#">Figure 5</a>	5 V	$48 \text{ ns} + (0.55 \text{ ns/pF})C_L$	-	75	150	ns
			10 V	$24 \text{ ns} + (0.23 \text{ ns/pF})C_L$	-	35	70	ns
			15 V	$17 \text{ ns} + (0.16 \text{ ns/pF})C_L$	-	25	50	ns

**Table 7. Dynamic characteristics ...continued** $V_{SS} = 0 \text{ V}$ ;  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ ; for test circuit see [Figure 6](#); unless otherwise specified.

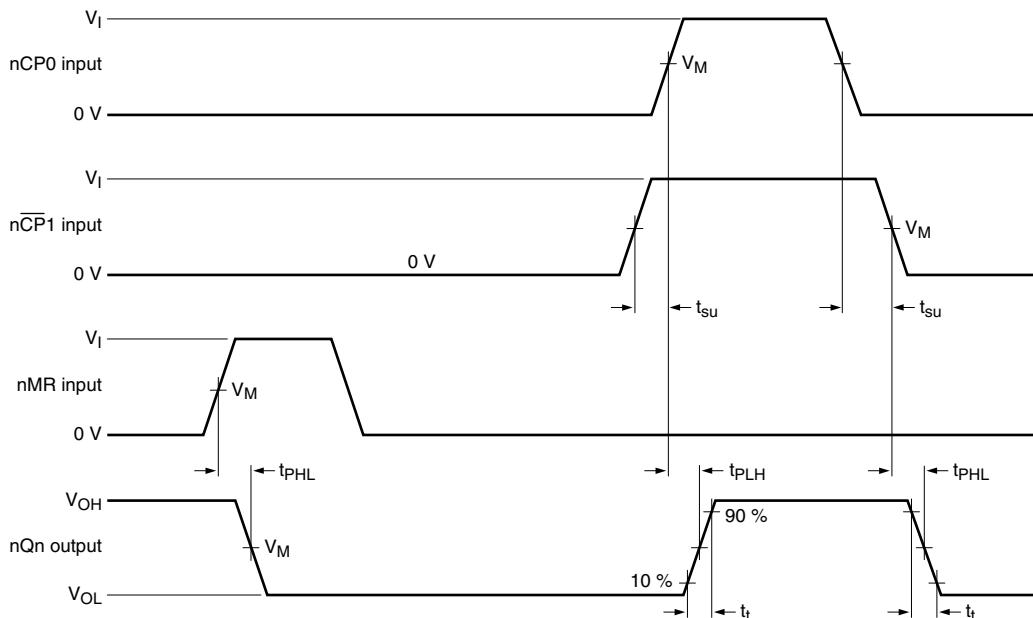
Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Typ	Max	Unit
$t_{PLH}$	LOW to HIGH propagation delay	nCP0, $\overline{nCP1} \rightarrow nQn$ ; see <a href="#">Figure 5</a>	5 V	[1] $83 \text{ ns} + (0.55 \text{ ns/pF})C_L$	-	110	220	ns
			10 V	$39 \text{ ns} + (0.23 \text{ ns/pF})C_L$	-	50	100	ns
			15 V	$32 \text{ ns} + (0.16 \text{ ns/pF})C_L$	-	40	80	ns
$t_f$	transition time	nQn; see <a href="#">Figure 5</a>	5 V	[1] $10 \text{ ns} + (1.00 \text{ ns/pF})C_L$	-	60	120	ns
			10 V	$9 \text{ ns} + (0.42 \text{ ns/pF})C_L$	-	30	60	ns
			15 V	$6 \text{ ns} + (0.28 \text{ ns/pF})C_L$	-	20	40	ns
$t_W$	pulse width	nCP0 input LOW; minimum width; see <a href="#">Figure 5</a>	5 V		60	30	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
		$\overline{nCP1}$ input HIGH; minimum width; see <a href="#">Figure 5</a>	5 V		60	30	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
		nMR input HIGH; minimum width; see <a href="#">Figure 5</a>	5 V		30	15	-	ns
			10 V		20	10	-	ns
			15 V		16	8	-	ns
		$nCP0 \rightarrow \overline{nCP1}$ ; see <a href="#">Figure 5</a>	5 V		50	25	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
		$\overline{nCP1} \rightarrow nCP0$ ; see <a href="#">Figure 5</a>	5 V		50	25	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
$t_{rec}$	recovery time	see <a href="#">Figure 5</a>	5 V		50	25	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
$f_{max}$	maximum frequency	nCP0, $\overline{nCP1}$ ; see <a href="#">Figure 5</a>	5 V		8	16	-	MHz
			10 V		15	30	-	MHz
			15 V		20	40	-	MHz

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown ( $C_L$  in pF).

**Table 8. Dynamic power dissipation  $P_D$**  $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0 \text{ V}$ ;  $t_f = t_f \leq 20 \text{ ns}$ ;  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ .

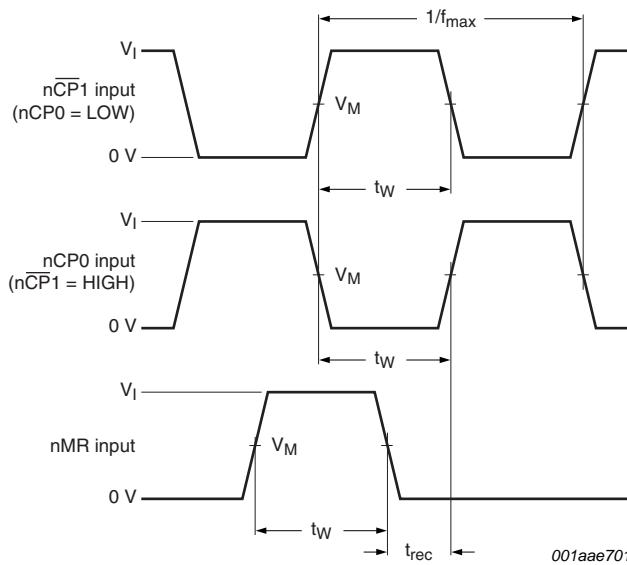
Symbol	Parameter	$V_{DD}$	Typical formula for $P_D$ ( $\mu\text{W}$ )	Where:
$P_D$	dynamic power dissipation	5 V	$P_D = 850 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	$f_i$ = input frequency in MHz,
		10 V	$P_D = 3800 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	$f_o$ = output frequency in MHz,
		15 V	$P_D = 10200 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF, $V_{DD}$ = supply voltage in V, $\Sigma(f_o \times C_L)$ = sum of the outputs.

## 12. Waveforms



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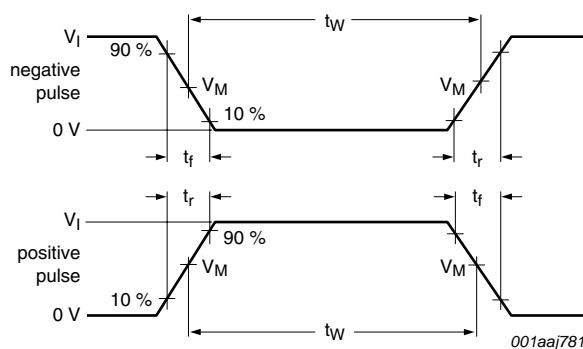
a. nCP0 and nCP1 set-up times, propagation delays and output transition times



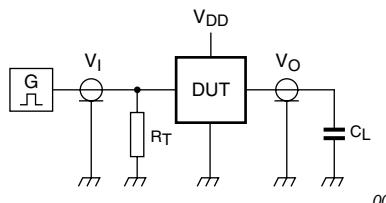
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b. nMR recovery time, minimum nCP0, nCP1, and nMR pulse widths and maximum frequency

Measurement points are given in [Table 9](#).The logic levels V<sub>OH</sub> and V<sub>OL</sub> are typical output voltage levels that occur with the output load.**Fig 5. Waveforms showing measurements for switching times**



a. Input waveforms



b. Test circuit

Test data is given in [Table 9](#).

Definitions for test circuit:

DUT = Device Under Test;

$C_L$  = Load capacitance including jig and probe capacitance;

$R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

Fig 6. Test circuit for measuring switching times

Table 9. Measurement points and test data

Supply voltage	Input			Load
	$V_I$	$V_M$	$t_r, t_f$	
5 V to 15 V	$V_{DD}$	$0.5V_I$	$\leq 20 \text{ ns}$	50 pF

## 13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

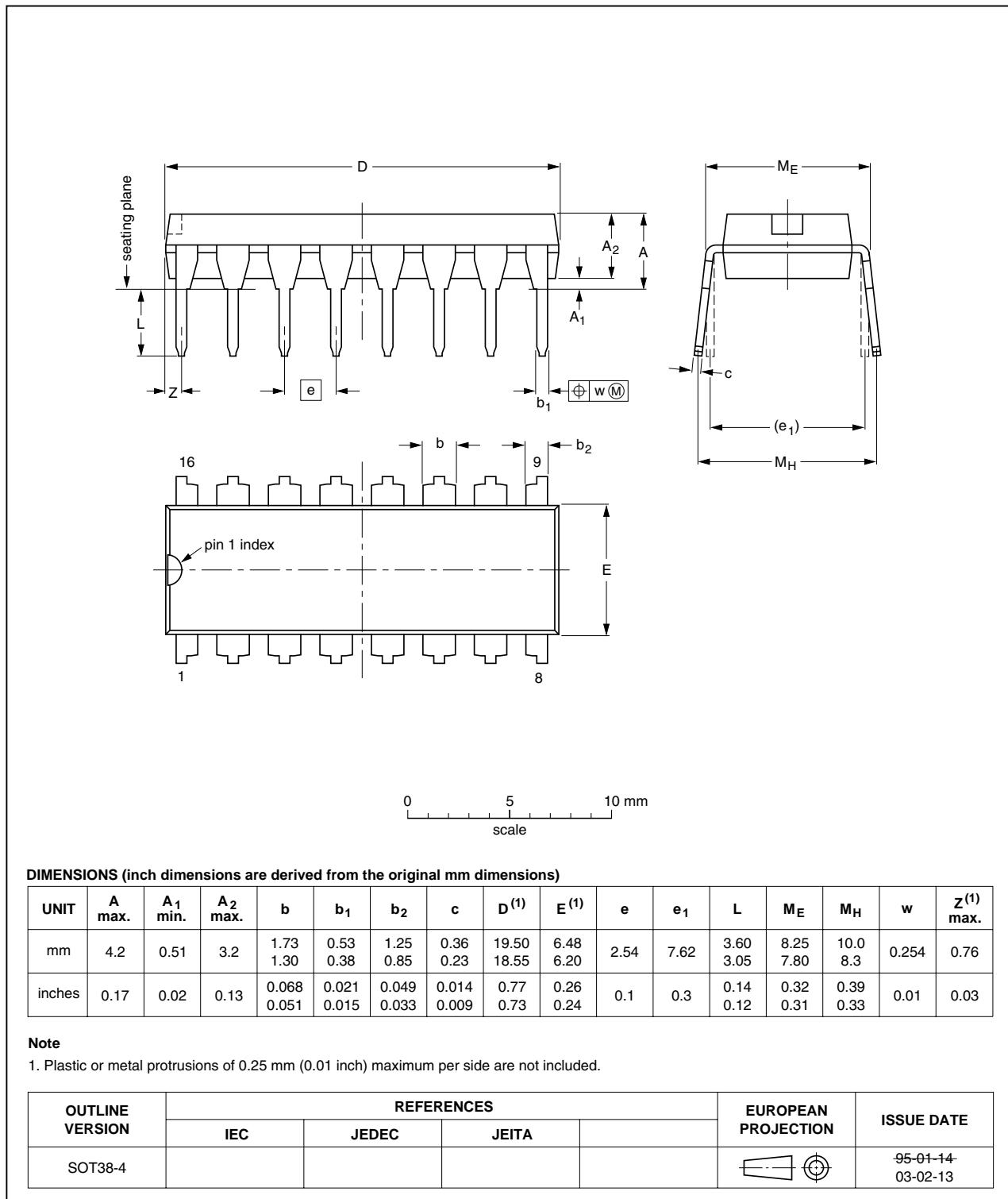


Fig 7. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

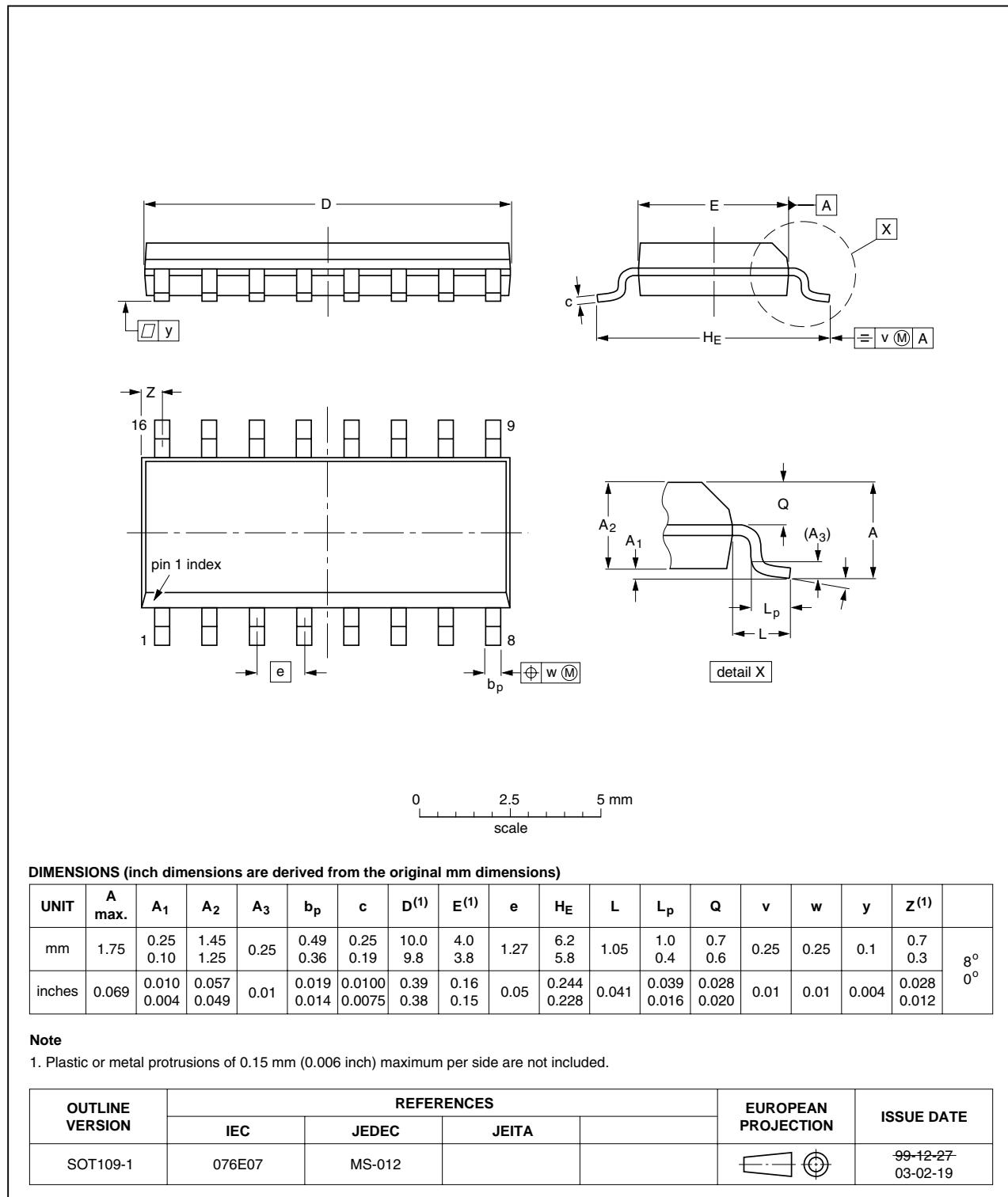


Fig 8. Package outline SOT109-1 (SO16)

## 14. Revision history

**Table 10. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4520B_5	20091210	Product data sheet	-	HEF4520B_4
Modifications:	• <a href="#">Section 9 “Recommended operating conditions” Δt/ΔV values updated.</a>			
HEF4520B_4	20090828	Product data sheet	-	HEF4520B_CNV_3
HEF4520B_CNV_3	19950101	Product specification	-	HEF4520B_CNV_2
HEF4520B_CNV_2	19950101	Product specification	-	-

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### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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